### TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

# 2 S C 3 1 2 2

### TV VHF RF AMPLIFIER APPLICATIONS

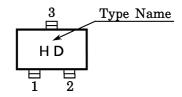
High Gain : G<sub>pe</sub>=24dB (Typ.) (f=200MHz)
 Low Noise : NF=2.0dB (Typ.) (f=200MHz)

Excellent Forward AGC Characteristics

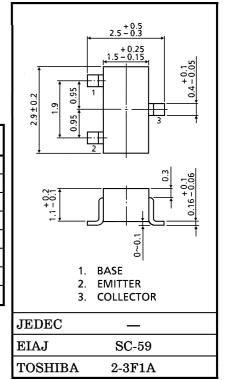
## MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$v_{CBO}$	30	V
Collector-Emitter Voltage	$v_{CEO}$	30	V
Emitter-Base Voltage	$V_{ m EBO}$	3	V
Collector Current	$^{\mathrm{I}}\mathrm{C}$	20	mA
Base Current	$I_{\mathbf{B}}$	10	mA
Collector Power Dissipation	$P_{\mathbf{C}}$	150	mW
Junction Temperature	$T_{j}$	125	$^{\circ}\mathrm{C}$
Storage Temperature Range	$T_{ m stg}$	-55~125	$^{\circ}\mathrm{C}$

# Marking



## Unit in mm



Weight: 0.012g

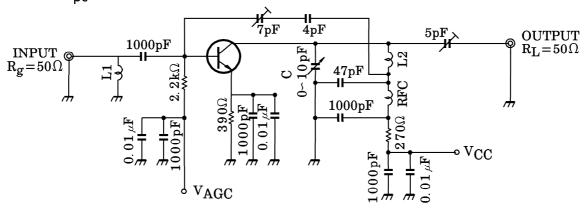
## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB} = 25V, I_{E} = 0$	_	_	100	nA
Emitter Cut-off Current	$I_{EBO}$	$V_{EB}=2V, I_{C}=0$	_	_	100	nA
Collector-Emitter Breakdown Voltage	V (BR) CEO	$I_{C}=1$ mA, $I_{B}=0$	30	_	_	V
DC Current Gain	$_{ m h_{FE}}$	$V_{\text{CE}} = 10V, I_{\text{C}} = 2\text{mA}$	60	150	300	_
Reverse Transfer Capacitance	Cre	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$	_	0.3	0.45	pF
Transition Frequency	${ m f_T}$	$V_{CE}=10V, I_{C}=2mA$	400	650	_	MHz
Power Gain	$G_{ m pe}$	$V_{CE}=12V, V_{AGC}=1.4V,$	20	24	28	dB
Noise Figure	NF	f=200MHz	_	2.0	3.2	dB
AGC Voltage	VAGC	$V_{CC}$ =12V, GR=30dB, f=200MHz (Note)	3.6	4.4	5.1	V

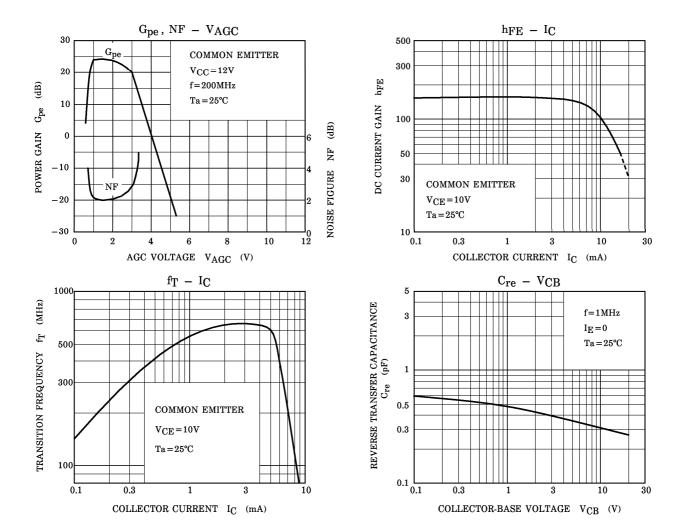
(Note)  $V_{\mbox{AGC}}$  measured by test circuit shown in Fig.1 when power gain is reduced to 30dB compared that of  $V_{\mbox{AGC}}$  at 1.4V.

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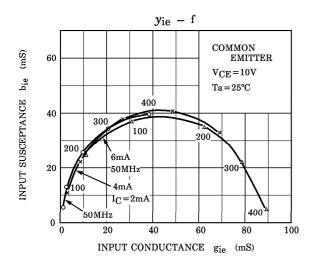
Fig.1 200MHz Gpe, NF TEST CIRCUIT

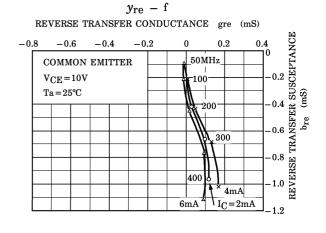


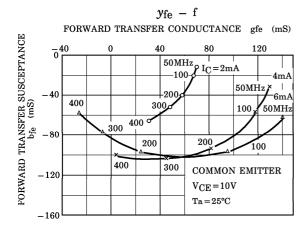
L1: RF Coil M-15T (TOKO Inc.) or EQUIVALENT L2: RF Coil M-25T (TOKO Inc.) or EQUIVALENT

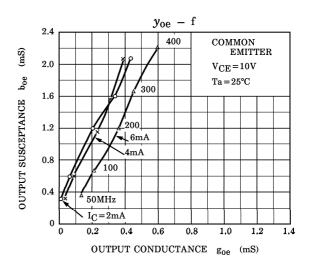


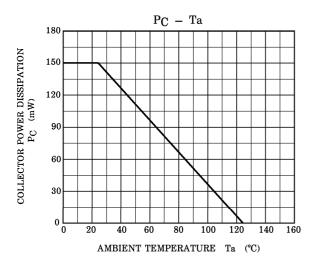
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